

DDR System Simulation: What Issue to Simulate

**Asian IBIS Summit
Tokyo, Japan
November 17, 2017**

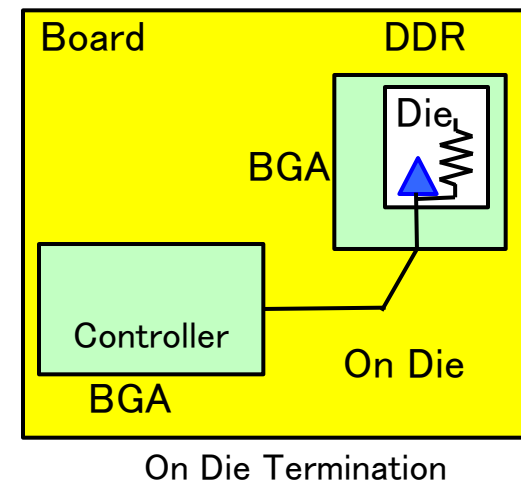
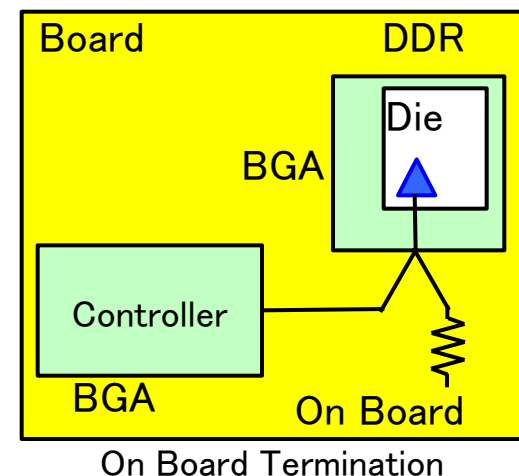
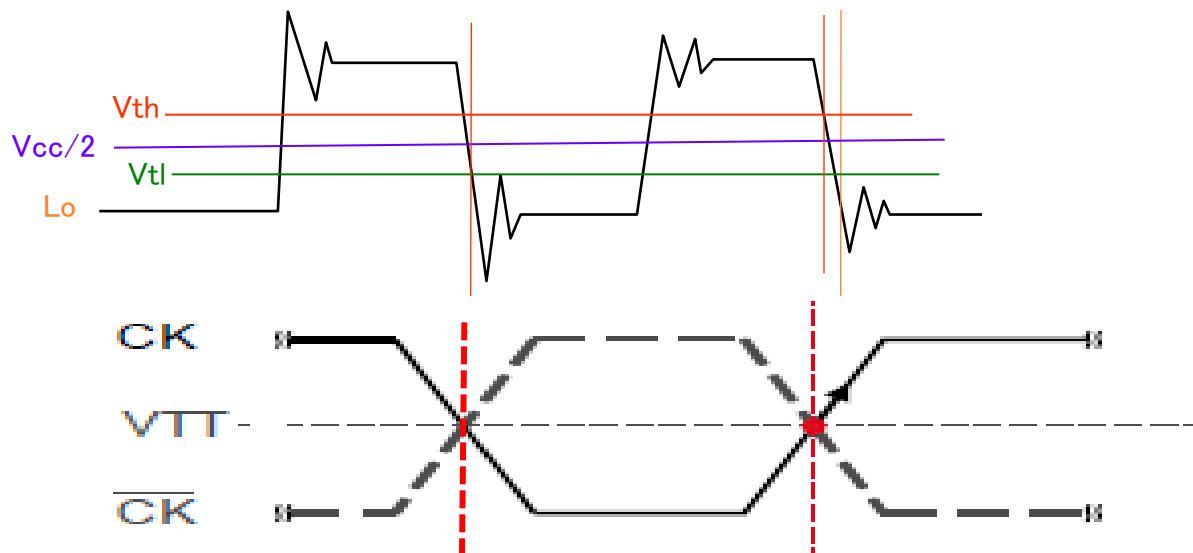
**Shinichi Maeda
KEI Systems**

JEDEC DDR Specifications

	DDR	DDR2	DDR3	DDR3L	DDR3U	DDR4
Vdd	2.5	1.8	1.5	1.35	1.25	1.2(IO) + 2.5(Core)
ODT(ohm)	N/A	50/75/150/OFF	20/30/40/60/120/OFF			34/40/48/60/80/120/240/OFF
Diff Clock	Single	Diff	Diff			Diff
DQS	Single	Single/Diff	Diff			Diff
Driver Z (ohm)	Full/Half	Full/Reduce	34/40			34/40/48
ADD/CMD Topology	T	T	Fly-by			Fly-by
Memory Size	~64Mbit	~4GBit	0.5~8GBit			2/4/8/16GBit
DQ Prefetch	2	4	8			8X2 (4x4)
Clock(MHz)	100~200	200~400	400~1066			800~1600
Data Speed (Mbps)	200~400	400~800	800~2133			1600~3200
Bus Width (Max)	4/8/16/32	4/8/16	4/8/16			4/8/16

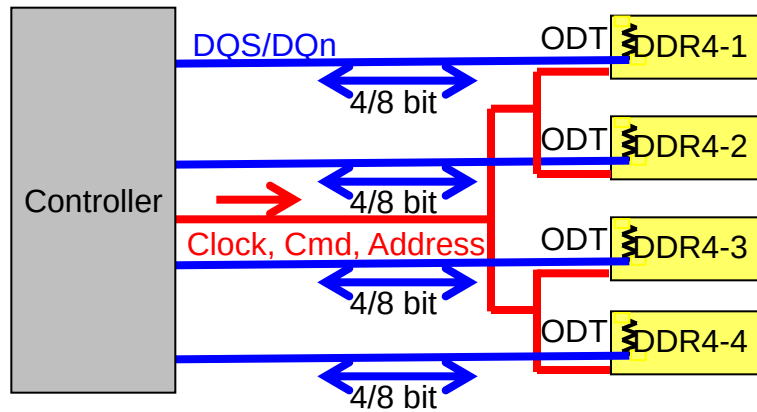
New Feature of DDR2

- ODT (DQ/DQn)
 - 50/75/150/OFF
 - Terminate to V_{tt} ($V_{dd}/2$)
- Output Characteristics
 - Full Strength/Reduced Strength
- Diff Clock/ Diff DQ

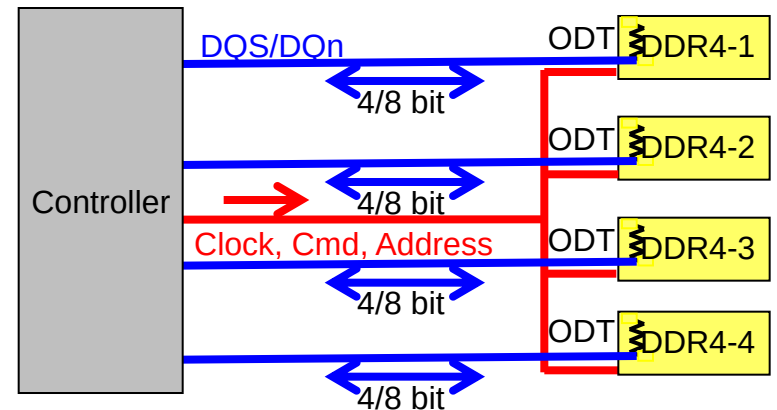


DDR2

- Topology (Clock/Add/CMD/CTRL)
 - Equal Delay
 - Terminate to Vtt ($V_{dd}/2$)



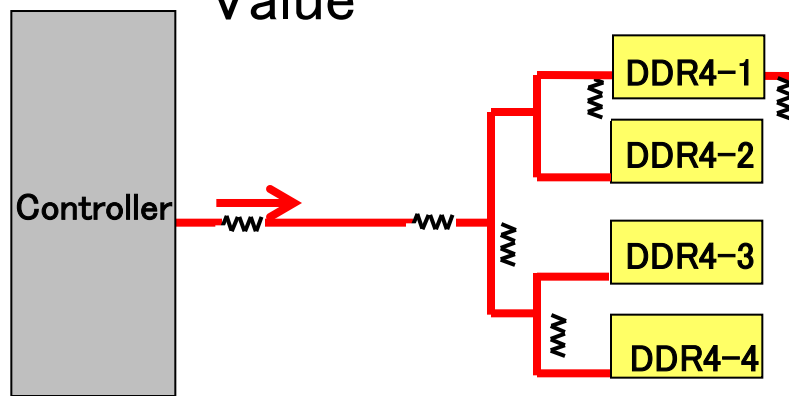
2 x 2 Branch



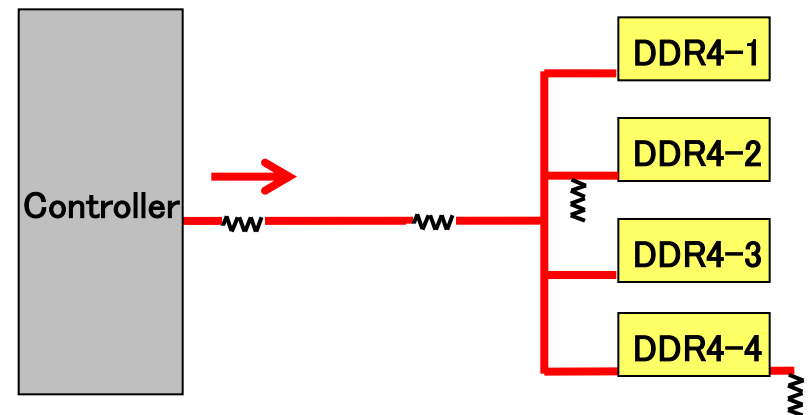
4 Branch

DDR2 Simulation

- Select best combination Driver and Receiver (ODT)
 - Full Strength/Reduced Strength $\leftrightarrow$ 50/75/150 ohm
 - 6 Combinations
- Topology (Clock/Add/CMD/CTRL)
 - Equal Delay
 - Termination
 - Place
 - Value



Clock, Cmd, Address

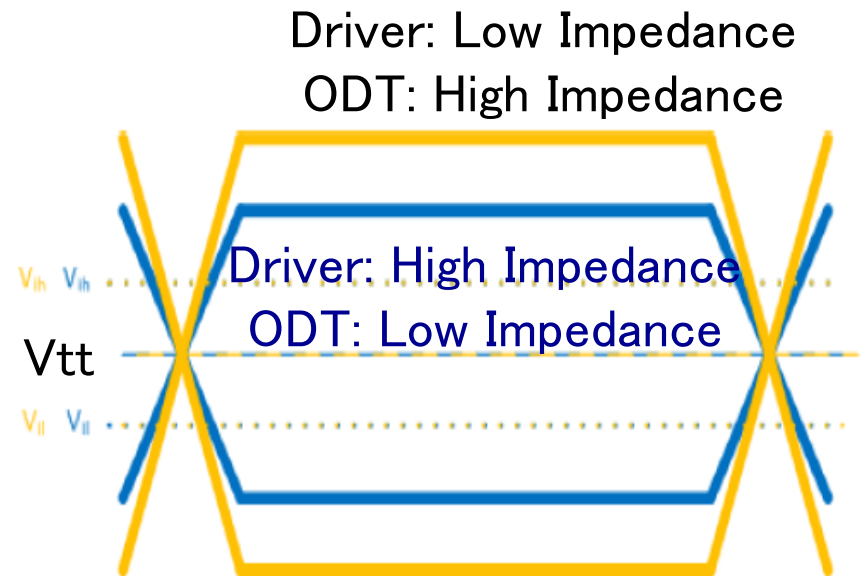


Clock, Cmd, Address

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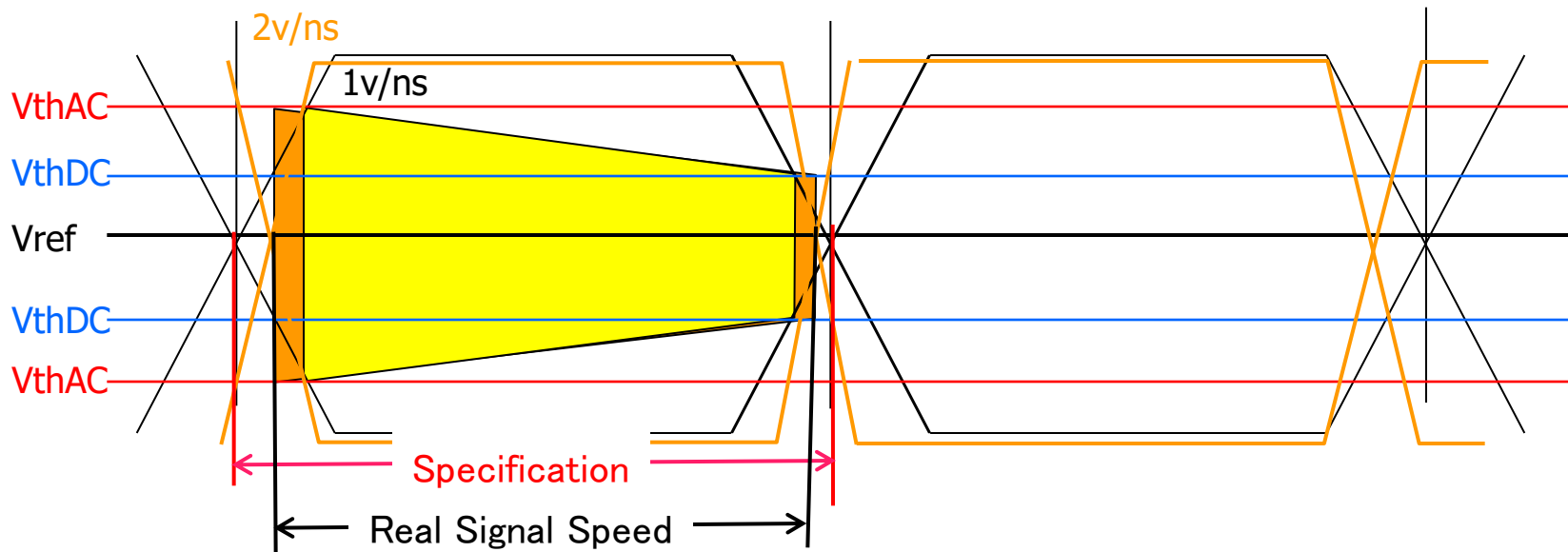
Combination Driver and Receiver

- Timing
 - Driver: Low/Receiver: High
 - High Signal Level. Fast, Shoot
 - High Power, Noisy (SSN, EMI)
 - Driver: Low/Receiver: High
 - High Signal Level. Fast, Shoot
- Driver: 34/40 ohm
- ODT: 50/75/150 ohm



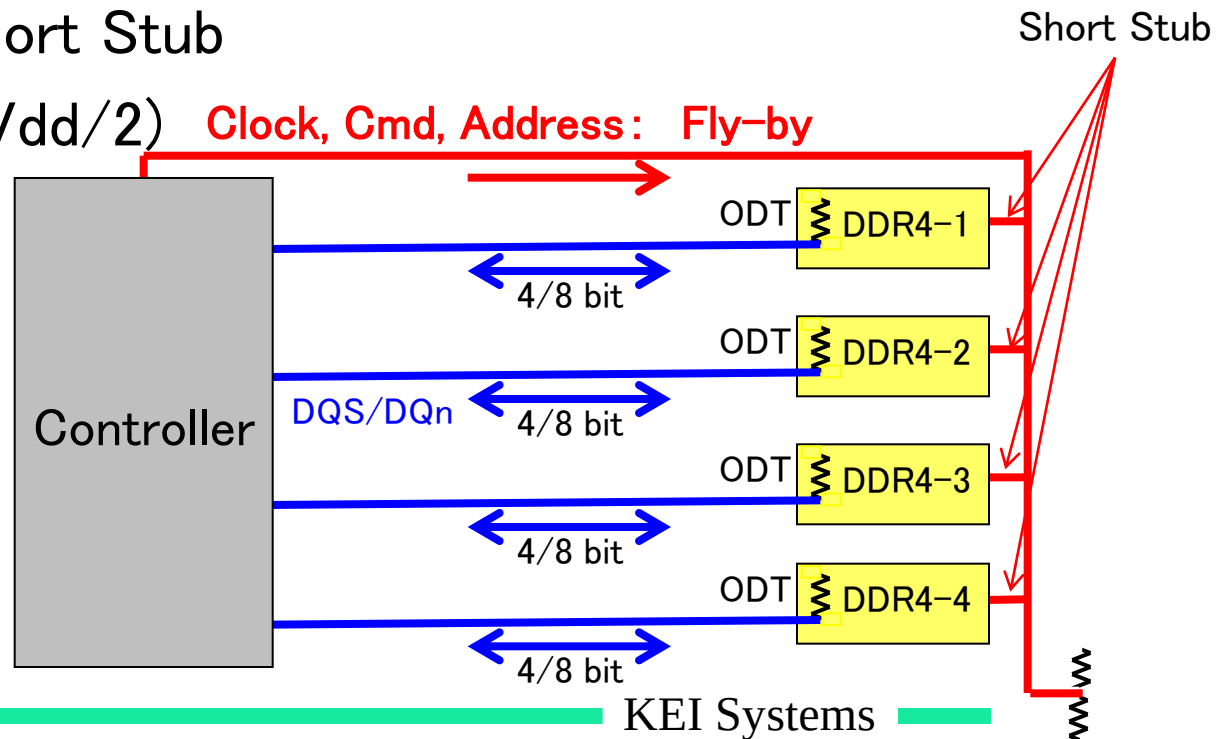
DDR2/DDR3 Timing Simulation

- Derating
 - Specification Assign on Vref Timing
 - IC Works on Threshold Voltage
 - Necessary to adjust the timing on Vref to Threshold Voltage
- Specification based on 1v/ns signal



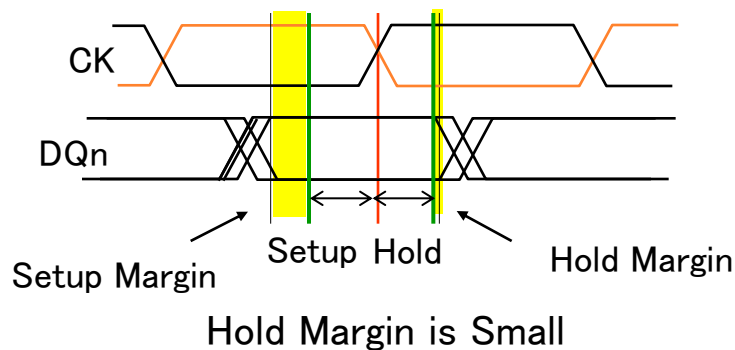
DDR3

- ODT
 - 20/30/40/60/120/OFF
- Output Characteristics
 - Full Strength/Reduced Strength
- Fly-by Topology (Clock/Add/CMD/CTRL)
 - Daisy-Gain with Short Stub
 - Terminate to Vtt ($V_{dd}/2$) **Clock, Cmd, Address: F**

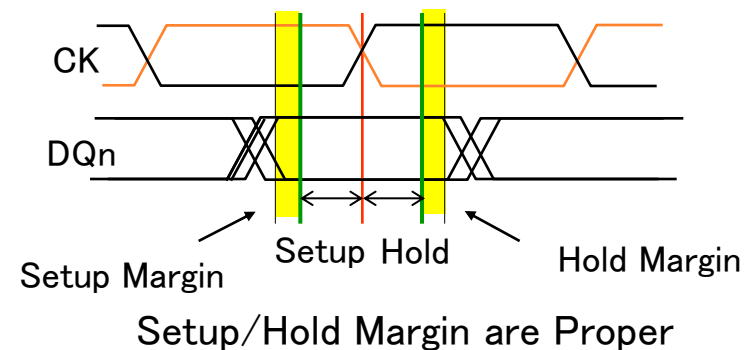


Simulation of DDR3 System

- Select best combination Driver and Receiver (ODT)
 - Full Strength/Reduced Strength – 20/30/40/60/120 ohm
 - 10 Combinations
- Fly-by
 - Effect of Stub Length
 - Leveraging
 - Read (Max. Timing Skew form 1st DDR to Last DDR) – Fly-by
 - Write (Option)



⇒
CK Phase shift



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DDR4 Features

- Faster (Two times faster than DDR3)
 - DDR3: 400MHz ~ 800MHz, 933, 1066 MHz
 - DDR4: 800MHz ~ 1600MHz (2400, 2666)
 - 2.5V Core Logic
- Lower Power
 - More ODT Value
 - Partial Refresh (LPDDR technology)
 - 1.2V Interface
 - POD Termination
 - DBI (Data Bus Inversion)

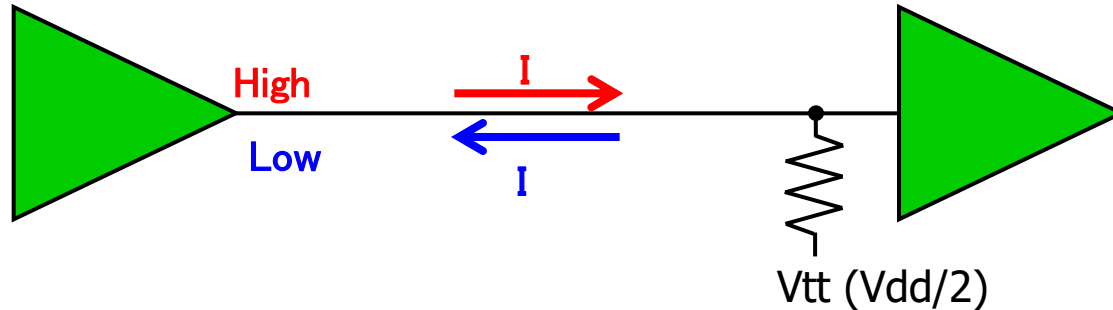
DDR4 Technology

- Same Technology of DDR3
 - ODT (34/40/48/60/80/120/240)
 - Fly by Wire
 - Output Impedance(34/40)
- New Feature
 - Multi-Purpose Register(MPR)

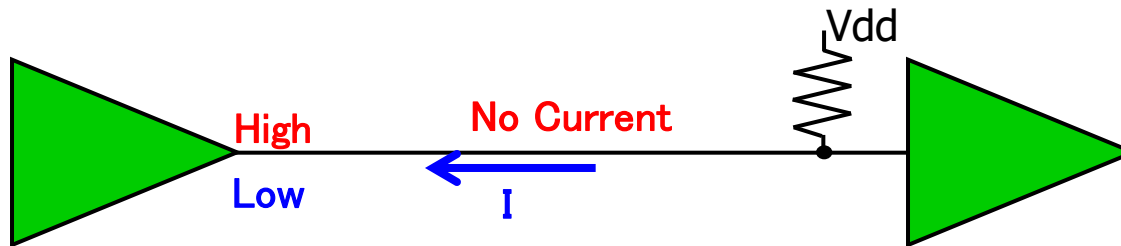
POD (Pseudo Open Drain) makes simulation difficult

POD

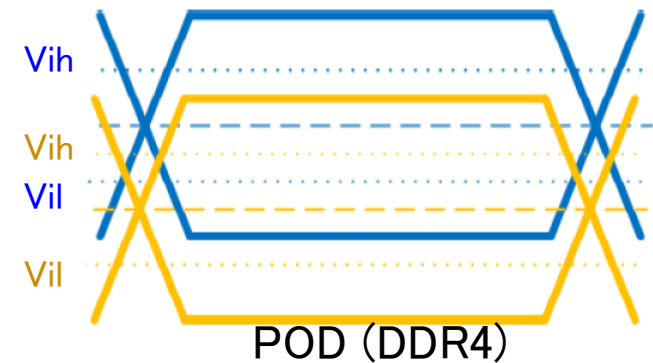
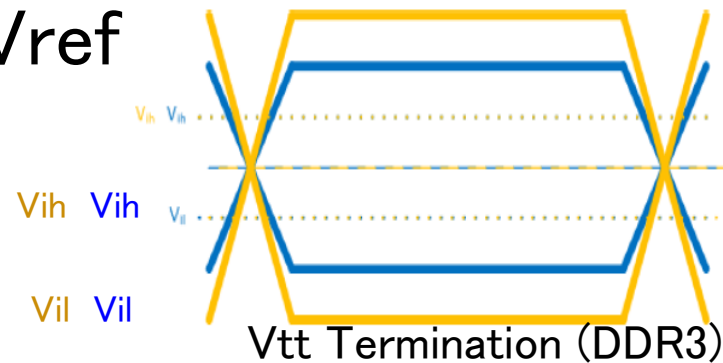
- ODT Termination Voltage: V_{tt} (DDR2/DDR3)



- POD (ODT Termination Voltage: V_{dd} (DDR4))



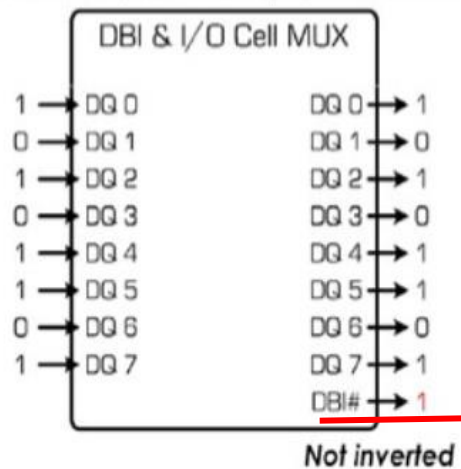
- POD Moves V_{ref}



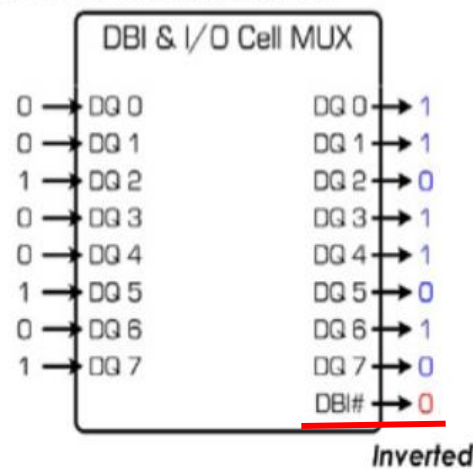
DBI (Data Bus Inversion)

- POD Termination
 - Low Level Data Drive High Current/High Level Data Drive no Current
 - When Low Level bits are Majority, Invert the Data
 - In Any Data, High bits are Majority
 - Simultaneous Switching: Less than 4 bits
 - Lower SSN

CASE 1: Less than or equal to 4 zeroes

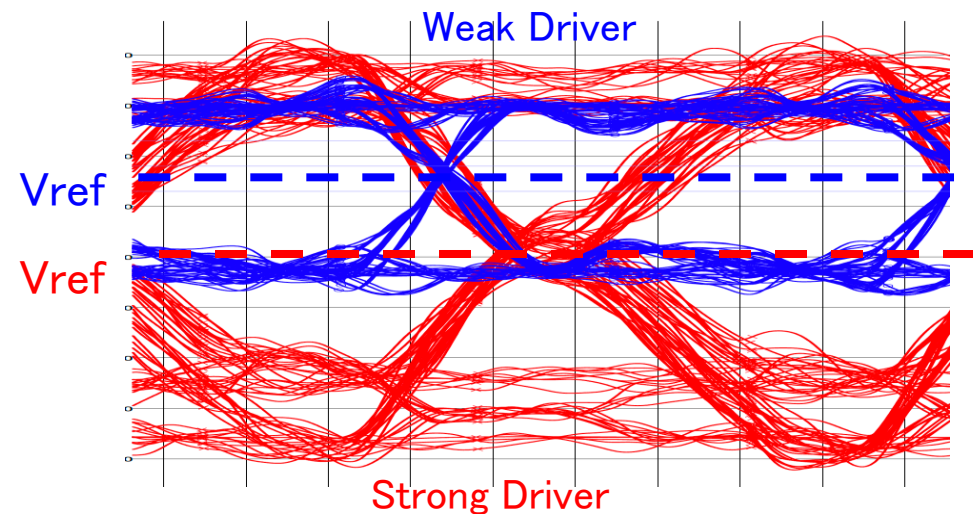


CASE 2: More than 4 zeroes



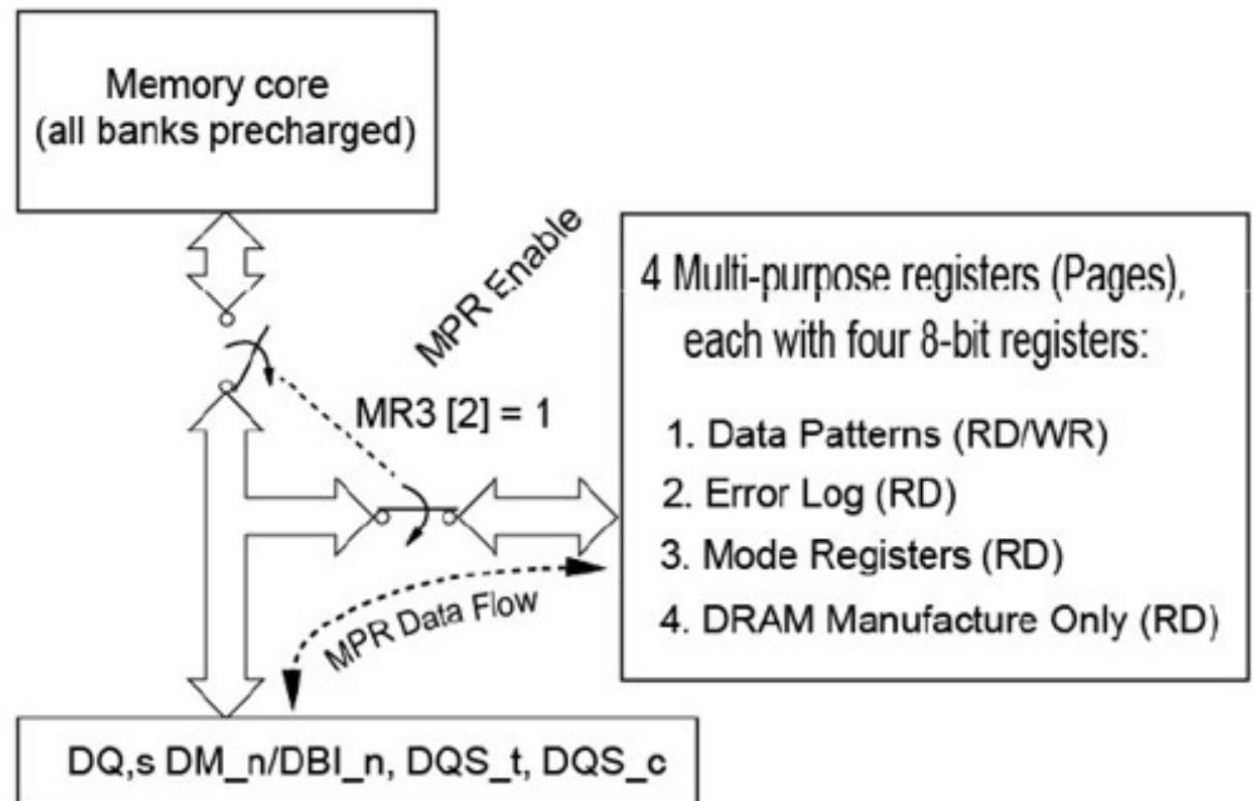
DDR4 System Design/Simulation

- DDR3 Methodology Can not be Used for DDR4 Design/Simulation
 - To Many combination of Driver-Receiver (18 Ways)
 - ODT: 34/40/48/60/120/240
 - Ron: 34/40/48
 - Vref Voltage is not fixed
- Vref, DQ Training
- ZQ Calibration



MPR (Multipurpose Register)

- Implement from DDR3
- Strongly Enhanced on DDR4
 - 4 4 Byte Registers
 - Training



DDR4 State Diagram

- **Set/Idle State and Read/Write State**

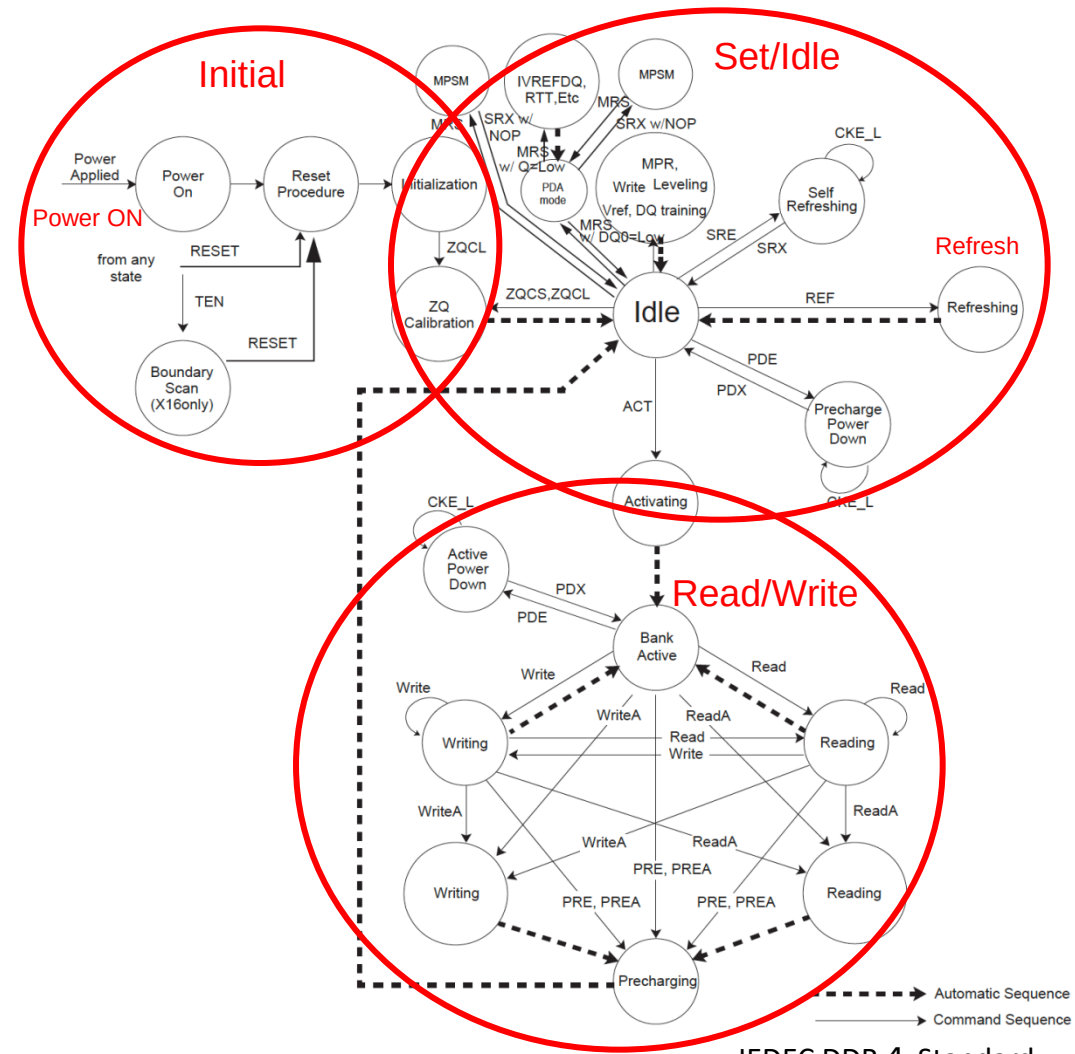
- Initial

- Initialize
- ZQ Calibration

- Set/Idle State

- Write Leveling
- ZQ Calibration
- Vref, DQ Training
- Refreshing

- Read/Write State



JEDEC DDR 4 Standard

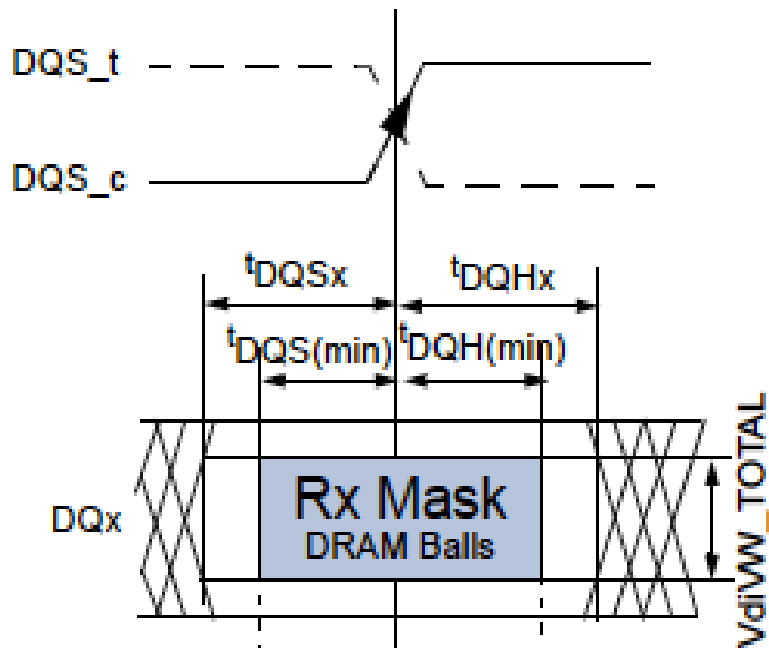
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Adapt Eye Mask

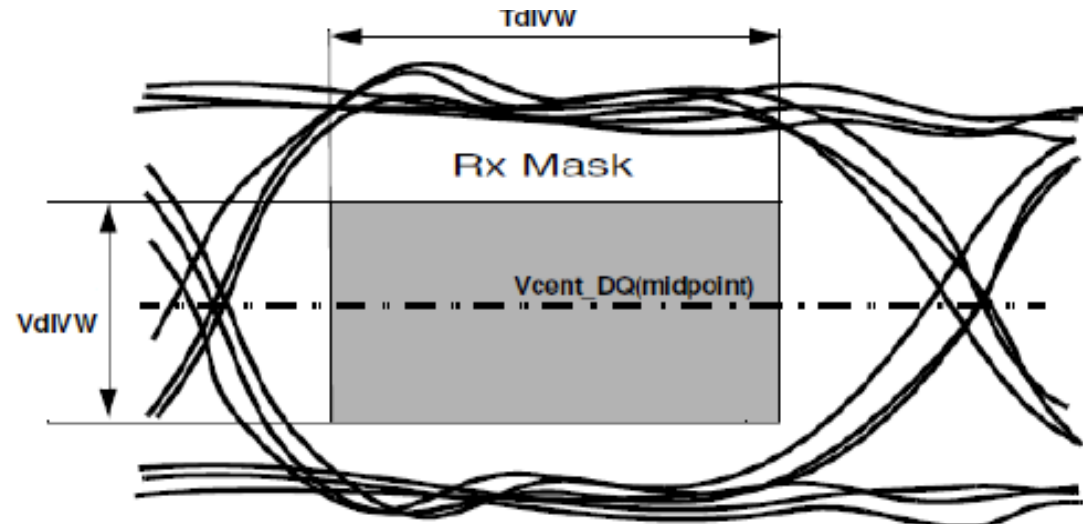
- Vref is Unstable
- Can't Fix Vref Based Timing Specification (DDR3)
 - No More Derating

DQS, DQS Data-in at DRAM ball

non Minimum Data-Eye / Maximum Rx Mask



DRAM Data Timing				
DQS_t,DQS_c to DQ skew, per group, per access	tDQSQ	-	TBD	-
DQS_t,DQS_c to DQ Skew deterministic, per group, per access	tDQSQ	-	TBD	-
DQ output hold time from DQS_t,DQS_c	tQH	TBD	-	TBD
DQ output hold time deterministic from DQS_t,DQS_c	tQH	TBD	-	TBD
DQS_t,DQS_c to DQ Skew total, per group, per access; DBI enabled	tDQSQ	-	TBD	-
DQ output hold time total from DQS_t, DQS_c; DBI enabled	tQH	TBD	-	TBD
DQ to DQ offset, per group, per access referenced to DQS_t, DQS_c	tDQSQ	TBD	TBD	TBD



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DDR4 Simulation is very difficult

- **Timing Analysis for Training**
 - ZQ Calibration
 - Vref Training
 - Write Leveling
- **SSN becomes more important**
 - Lower voltage (1.2V)
 - Faster signal (dv/dt)
- **X' talk**
 - Faster signal (dv/dt)
- **Package Model**
 - Signal skew of In Package connection
 - In package X' talk (Bigger than on board connection)
 - Stub for Fly-by

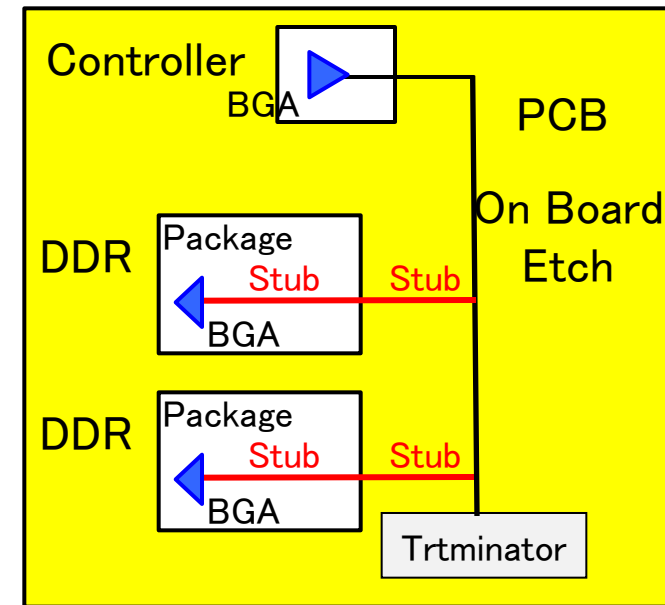
IBIS Model for DDR4 Simulation



- Power Aware (IBIS 5.0)
- Vref Training/Write Leveling
 - Eye Mask



- Overclock
- Support DQ Training
 - How to determine best Driver–Receiver simulation model
- Fly-by Support
 - In–Package Stub



DDR5

- JEDEC Already working DDR5 Specification
 - Focus in 2018
 - Products in 2020?
 - x2 Faster than DDR4
 - DFE (Decision Feedback Equalizer)
 - Reduce ISI
 - More Training
 - Bigger Memory size
 - Power Reduce Technology
 - Analog Filter? (to reduce ISI jitter)
- Hard to Simulate

Conclusion

- **DDR2 System Simulation**
 - **ADD/CMD/CTRL Topology**
 - **Combination of Driver/ODT**
 - **Sign-off Analysis**
- **DDR3 System Simulation**
 - **ADD/CMD/CTRL Fly-by Topology**
 - **Combination of Driver/ODT**
 - **Sign-off Analysis**
- **DDR4 System Simulation**
 - **ADD/CMD/CTRL Fly-by Topology (in Package Etch)**
 - **Combination of Driver/ODT (Too many combination to Simulate)**
 - **Can't execute Sign-off Analysis (Can't follow Training Result)**
 - **Power aware/Over Clock**
- **DDR5 System Simulation ?**
 - **More Intelligent I/F specification (More training functions)**
 - **Analog Filter Circuit? (IBIS AMI?)**